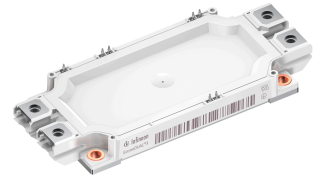


## Final datasheet

### EconoDUAL™3 module with Trench/Fieldstop IGBT4 and emitter controlled diode and PressFIT / NTC / TIM

#### Features

- Electrical features
  - $V_{CES} = 1200\text{ V}$
  - $I_{C\text{ nom}} = 600\text{ A} / I_{CRM} = 1200\text{ A}$
  - Low  $V_{CE,sat}$
  - $T_{vj,op} = 150^{\circ}\text{C}$
  - $V_{CE,sat}$  with positive temperature coefficient
  - Suitable Infineon gate drivers can be found under <https://www.infineon.com/gdfinder>
- Mechanical features
  - High power density
  - Isolated base plate
  - Standard housing
  - Pre-applied thermal interface material



#### Potential applications

- High-power converters
- Motor drives
- Servo drives
- UPS systems
- Wind turbines

#### Product validation

- Qualified for industrial applications according to the relevant tests of IEC 60747, 60749 and 60068

#### Description

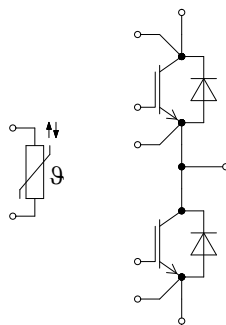


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## 1 Package

**Table 1** Insulation coordination

| Parameter                           | Symbol                  | Note or test condition                         | Values    | Unit |
|-------------------------------------|-------------------------|------------------------------------------------|-----------|------|
| Isolation test voltage              | $V_{ISOL}$              | RMS, $f = 50 \text{ Hz}$ , $t = 1 \text{ min}$ | 2.5       | kV   |
| Isolation test voltage NTC          | $V_{ISOL(NTC)}$         | RMS, $f = 50 \text{ Hz}$ , $t = 1 \text{ min}$ | 2.5       | kV   |
| Material of module baseplate        |                         |                                                | Cu        |      |
| Internal isolation                  |                         | basic insulation (class 1, IEC 61140)          | $Al_2O_3$ |      |
| Creepage distance                   | $d_{Creep \text{ nom}}$ | terminal to baseplate, nom.                    | > 15      | mm   |
| Creepage distance                   | $d_{Creep \text{ min}}$ | terminal to baseplate, min.                    | 14.7      | mm   |
| Creepage distance                   | $d_{Creep \text{ nom}}$ | terminal to terminal, nom.                     | > 19.3    | mm   |
| Creepage distance                   | $d_{Creep \text{ min}}$ | terminal to terminal, min.                     | 19.3      | mm   |
| Clearance                           | $d_{Clear \text{ nom}}$ | terminal to baseplate, nom.                    | > 12.5    | mm   |
| Clearance                           | $d_{Clear \text{ min}}$ | terminal to baseplate, min.                    | 12.5      | mm   |
| Clearance                           | $d_{Clear \text{ nom}}$ | terminal to terminal, nom.                     | > 10      | mm   |
| Clearance                           | $d_{Clear \text{ min}}$ | terminal to terminal, min.                     | 9.6       | mm   |
| Comparative tracking index          | $CTI$                   |                                                | > 200     |      |
| Relative thermal index (electrical) | $RTI$                   | housing                                        | 140       | °C   |

**Table 2** Characteristic values

| Parameter                                | Symbol        | Note or test condition                          |           | Values |      |      | Unit |
|------------------------------------------|---------------|-------------------------------------------------|-----------|--------|------|------|------|
|                                          |               |                                                 |           | Min.   | Typ. | Max. |      |
| Stray inductance module                  | $L_{sCE}$     |                                                 |           |        | 20   |      | nH   |
| Module lead resistance, terminals - chip | $R_{CC'+EE'}$ | $T_H = 25\text{ }^{\circ}\text{C}$ , per switch |           |        | 1.1  |      | mΩ   |
| Storage temperature                      | $T_{stg}$     |                                                 |           | -40    |      | 125  | °C   |
| Maximum baseplate operation temperature  | $T_{BPmax}$   |                                                 |           |        |      | 125  | °C   |
| Mounting torque for module mounting      | $M$           | - Mounting according to valid application note  | M5, Screw | 3      |      | 6    | Nm   |
| Terminal connection torque               | $M$           | - Mounting according to valid application note  | M6, Screw | 3      |      | 6    | Nm   |
| Weight                                   | $G$           |                                                 |           |        | 345  |      | g    |

**Note:** Storage and shipment of modules with TIM => see AN2012-07

## 2 IGBT, Inverter

**Table 3** Maximum rated values

| Parameter                         | Symbol    | Note or test condition              |                         | Values   | Unit |
|-----------------------------------|-----------|-------------------------------------|-------------------------|----------|------|
| Collector-emitter voltage         | $V_{CES}$ |                                     | $T_{vj} = 25\text{ °C}$ | 1200     | V    |
| Continuous DC collector current   | $I_{CDC}$ | $T_{vj\text{ max}} = 175\text{ °C}$ | $T_H = 75\text{ °C}$    | 600      | A    |
| Repetitive peak collector current | $I_{CRM}$ | $t_p$ limited by $T_{vj\text{ op}}$ |                         | 1200     | A    |
| Gate-emitter peak voltage         | $V_{GES}$ |                                     |                         | $\pm 20$ | V    |

**Table 4** Characteristic values

| Parameter                            | Symbol              | Note or test condition                                                                                          |                          | Values |       |      | Unit          |
|--------------------------------------|---------------------|-----------------------------------------------------------------------------------------------------------------|--------------------------|--------|-------|------|---------------|
|                                      |                     |                                                                                                                 |                          | Min.   | Typ.  | Max. |               |
| Collector-emitter saturation voltage | $V_{CE\text{ sat}}$ | $I_C = 600\text{ A}$ , $V_{GE} = 15\text{ V}$                                                                   | $T_{vj} = 25\text{ °C}$  |        | 1.75  | 2.10 | V             |
|                                      |                     |                                                                                                                 | $T_{vj} = 125\text{ °C}$ |        | 2.00  |      |               |
|                                      |                     |                                                                                                                 | $T_{vj} = 150\text{ °C}$ |        | 2.05  |      |               |
| Gate threshold voltage               | $V_{GETh}$          | $I_C = 23\text{ mA}$ , $V_{CE} = V_{GE}$ , $T_{vj} = 25\text{ °C}$                                              |                          | 5.20   | 5.80  | 6.40 | V             |
| Gate charge                          | $Q_G$               | $V_{GE} = \pm 15\text{ V}$ , $T_{vj} = 25\text{ °C}$                                                            |                          |        | 4.4   |      | $\mu\text{C}$ |
| Internal gate resistor               | $R_{Gint}$          | $T_{vj} = 25\text{ °C}$                                                                                         |                          |        | 1.2   |      | $\Omega$      |
| Input capacitance                    | $C_{ies}$           | $f = 1000\text{ kHz}$ , $T_{vj} = 25\text{ °C}$ , $V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$                |                          |        | 37    |      | nF            |
| Reverse transfer capacitance         | $C_{res}$           | $f = 1000\text{ kHz}$ , $T_{vj} = 25\text{ °C}$ , $V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$                |                          |        | 2.05  |      | nF            |
| Collector-emitter cut-off current    | $I_{CES}$           | $V_{CE} = 1200\text{ V}$ , $V_{GE} = 0\text{ V}$                                                                | $T_{vj} = 25\text{ °C}$  |        |       | 3    | mA            |
| Gate-emitter leakage current         | $I_{GES}$           | $V_{CE} = 0\text{ V}$ , $V_{GE} = 20\text{ V}$ , $T_{vj} = 25\text{ °C}$                                        |                          |        |       | 400  | nA            |
| Turn-on delay time (inductive load)  | $t_{don}$           | $I_C = 600\text{ A}$ , $V_{CC} = 600\text{ V}$ ,<br>$V_{GE} = \pm 15\text{ V}$ , $R_{Gon} = 1.5\text{ }\Omega$  | $T_{vj} = 25\text{ °C}$  |        | 0.160 |      | $\mu\text{s}$ |
|                                      |                     |                                                                                                                 | $T_{vj} = 125\text{ °C}$ |        | 0.210 |      |               |
|                                      |                     |                                                                                                                 | $T_{vj} = 150\text{ °C}$ |        | 0.210 |      |               |
| Rise time (inductive load)           | $t_r$               | $I_C = 600\text{ A}$ , $V_{CC} = 600\text{ V}$ ,<br>$V_{GE} = \pm 15\text{ V}$ , $R_{Gon} = 1.5\text{ }\Omega$  | $T_{vj} = 25\text{ °C}$  |        | 0.090 |      | $\mu\text{s}$ |
|                                      |                     |                                                                                                                 | $T_{vj} = 125\text{ °C}$ |        | 0.090 |      |               |
|                                      |                     |                                                                                                                 | $T_{vj} = 150\text{ °C}$ |        | 0.100 |      |               |
| Turn-off delay time (inductive load) | $t_{doff}$          | $I_C = 600\text{ A}$ , $V_{CC} = 600\text{ V}$ ,<br>$V_{GE} = \pm 15\text{ V}$ , $R_{Goff} = 1.5\text{ }\Omega$ | $T_{vj} = 25\text{ °C}$  |        | 0.480 |      | $\mu\text{s}$ |
|                                      |                     |                                                                                                                 | $T_{vj} = 125\text{ °C}$ |        | 0.610 |      |               |
|                                      |                     |                                                                                                                 | $T_{vj} = 150\text{ °C}$ |        | 0.650 |      |               |

(table continues...)

**Table 4** (continued) Characteristic values

| Parameter                                 | Symbol      | Note or test condition                                                                                                                                                                                           | Values                                                   |       |       | Unit          |
|-------------------------------------------|-------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------|-------|-------|---------------|
|                                           |             |                                                                                                                                                                                                                  | Min.                                                     | Typ.  | Max.  |               |
| Fall time (inductive load)                | $t_f$       | $I_C = 600 \text{ A}$ , $V_{CC} = 600 \text{ V}$ ,<br>$V_{GE} = \pm 15 \text{ V}$ , $R_{Goff} = 1.5 \Omega$                                                                                                      | $T_{vj} = 25 \text{ °C}$                                 | 0.070 |       | $\mu\text{s}$ |
|                                           |             |                                                                                                                                                                                                                  | $T_{vj} = 125 \text{ °C}$                                | 0.110 |       |               |
|                                           |             |                                                                                                                                                                                                                  | $T_{vj} = 150 \text{ °C}$                                | 0.120 |       |               |
| Turn-on energy loss per pulse             | $E_{on}$    | $I_C = 600 \text{ A}$ , $V_{CC} = 600 \text{ V}$ ,<br>$L_\sigma = 35 \text{ nH}$ , $V_{GE} = \pm 15 \text{ V}$ ,<br>$R_{Gon} = 1.5 \Omega$ , $di/dt = 5100 \text{ A}/\mu\text{s}$ ( $T_{vj} = 150 \text{ °C}$ )  | $T_{vj} = 25 \text{ °C}$                                 | 62.5  |       | mJ            |
|                                           |             |                                                                                                                                                                                                                  | $T_{vj} = 125 \text{ °C}$                                | 83    |       |               |
|                                           |             |                                                                                                                                                                                                                  | $T_{vj} = 150 \text{ °C}$                                | 90    |       |               |
| Turn-off energy loss per pulse            | $E_{off}$   | $I_C = 600 \text{ A}$ , $V_{CC} = 600 \text{ V}$ ,<br>$L_\sigma = 35 \text{ nH}$ , $V_{GE} = \pm 15 \text{ V}$ ,<br>$R_{Goff} = 1.5 \Omega$ , $dv/dt = 3700 \text{ V}/\mu\text{s}$ ( $T_{vj} = 150 \text{ °C}$ ) | $T_{vj} = 25 \text{ °C}$                                 | 47    |       | mJ            |
|                                           |             |                                                                                                                                                                                                                  | $T_{vj} = 125 \text{ °C}$                                | 72    |       |               |
|                                           |             |                                                                                                                                                                                                                  | $T_{vj} = 150 \text{ °C}$                                | 79.5  |       |               |
| SC data                                   | $I_{SC}$    | $V_{GE} \leq 15 \text{ V}$ , $V_{CC} = 800 \text{ V}$ ,<br>$V_{CEmax} = V_{CES} - L_{sCE} \cdot di/dt$                                                                                                           | $t_p \leq 10 \mu\text{s}$ ,<br>$T_{vj} = 150 \text{ °C}$ | 2400  |       | A             |
| Thermal resistance, junction to heat sink | $R_{thJH}$  | per IGBT, Valid with IFX pre-applied Thermal Interface Material                                                                                                                                                  |                                                          |       | 0.065 | K/W           |
| Temperature under switching conditions    | $T_{vj op}$ |                                                                                                                                                                                                                  | -40                                                      |       | 150   | °C            |

### 3 Diode, Inverter

**Table 5** Maximum rated values

| Parameter                       | Symbol    | Note or test condition                      | Values                    | Unit                 |
|---------------------------------|-----------|---------------------------------------------|---------------------------|----------------------|
| Repetitive peak reverse voltage | $V_{RRM}$ | $T_{vj} = 25 \text{ °C}$                    | 1200                      | V                    |
| Continuous DC forward current   | $I_F$     |                                             | 600                       | A                    |
| Repetitive peak forward current | $I_{FRM}$ | $t_p = 1 \text{ ms}$                        | 1200                      | A                    |
| $I^2t$ - value                  | $I^2t$    | $t_p = 10 \text{ ms}$ , $V_R = 0 \text{ V}$ | $T_{vj} = 125 \text{ °C}$ | $\text{A}^2\text{s}$ |
|                                 |           |                                             | $T_{vj} = 150 \text{ °C}$ |                      |

**Table 6** Characteristic values

| Parameter       | Symbol | Note or test condition                         | Values                    |      |      | Unit |
|-----------------|--------|------------------------------------------------|---------------------------|------|------|------|
|                 |        |                                                | Min.                      | Typ. | Max. |      |
| Forward voltage | $V_F$  | $I_F = 600 \text{ A}$ , $V_{GE} = 0 \text{ V}$ | $T_{vj} = 25 \text{ °C}$  | 1.65 | 2.10 | V    |
|                 |        |                                                | $T_{vj} = 125 \text{ °C}$ | 1.65 |      |      |
|                 |        |                                                | $T_{vj} = 150 \text{ °C}$ | 1.65 |      |      |

(table continues...)

**Table 6** (continued) Characteristic values

| Parameter                                 | Symbol             | Note or test condition                                                                                                                            | Values                   |      |       | Unit          |
|-------------------------------------------|--------------------|---------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------|------|-------|---------------|
|                                           |                    |                                                                                                                                                   | Min.                     | Typ. | Max.  |               |
| Peak reverse recovery current             | $I_{RM}$           | $V_{CC} = 600\text{ V}$ , $I_F = 600\text{ A}$ ,<br>$V_{GE} = -15\text{ V}$ , $-di_F/dt = 5100\text{ A}/\mu\text{s}$ ( $T_{vj} = 150\text{ °C}$ ) | $T_{vj} = 25\text{ °C}$  | 290  |       | A             |
|                                           |                    |                                                                                                                                                   | $T_{vj} = 125\text{ °C}$ | 420  |       |               |
|                                           |                    |                                                                                                                                                   | $T_{vj} = 150\text{ °C}$ | 450  |       |               |
| Recovered charge                          | $Q_r$              | $V_{CC} = 600\text{ V}$ , $I_F = 600\text{ A}$ ,<br>$V_{GE} = -15\text{ V}$ , $-di_F/dt = 5100\text{ A}/\mu\text{s}$ ( $T_{vj} = 150\text{ °C}$ ) | $T_{vj} = 25\text{ °C}$  | 62   |       | $\mu\text{C}$ |
|                                           |                    |                                                                                                                                                   | $T_{vj} = 125\text{ °C}$ | 115  |       |               |
|                                           |                    |                                                                                                                                                   | $T_{vj} = 150\text{ °C}$ | 130  |       |               |
| Reverse recovery energy                   | $E_{rec}$          | $V_{CC} = 600\text{ V}$ , $I_F = 600\text{ A}$ ,<br>$V_{GE} = -15\text{ V}$ , $-di_F/dt = 5100\text{ A}/\mu\text{s}$ ( $T_{vj} = 150\text{ °C}$ ) | $T_{vj} = 25\text{ °C}$  | 22   |       | mJ            |
|                                           |                    |                                                                                                                                                   | $T_{vj} = 125\text{ °C}$ | 44   |       |               |
|                                           |                    |                                                                                                                                                   | $T_{vj} = 150\text{ °C}$ | 51   |       |               |
| Thermal resistance, junction to heat sink | $R_{thJH}$         | per diode, Valid with IFX pre-applied Thermal Interface Material                                                                                  |                          |      | 0.105 | K/W           |
| Temperature under switching conditions    | $T_{vj\text{ op}}$ |                                                                                                                                                   | -40                      |      | 150   | °C            |

## 4 NTC-Thermistor

**Table 7** Characteristic values

| Parameter              | Symbol       | Note or test condition                                       | Values |      |      | Unit |
|------------------------|--------------|--------------------------------------------------------------|--------|------|------|------|
|                        |              |                                                              | Min.   | Typ. | Max. |      |
| Rated resistance       | $R_{25}$     | $T_{NTC} = 25\text{ °C}$                                     |        | 5    |      | kΩ   |
| Deviation of $R_{100}$ | $\Delta R/R$ | $T_{NTC} = 100\text{ °C}$ , $R_{100} = 493\text{ Ω}$         | -5     |      | 5    | %    |
| Power dissipation      | $P_{25}$     | $T_{NTC} = 25\text{ °C}$                                     |        |      | 20   | mW   |
| B-value                | $B_{25/50}$  | $R_2 = R_{25} \exp[B_{25/50}(1/T_2 - 1/(298,15\text{ K}))]$  |        | 3375 |      | K    |
| B-value                | $B_{25/80}$  | $R_2 = R_{25} \exp[B_{25/80}(1/T_2 - 1/(298,15\text{ K}))]$  |        | 3411 |      | K    |
| B-value                | $B_{25/100}$ | $R_2 = R_{25} \exp[B_{25/100}(1/T_2 - 1/(298,15\text{ K}))]$ |        | 3433 |      | K    |

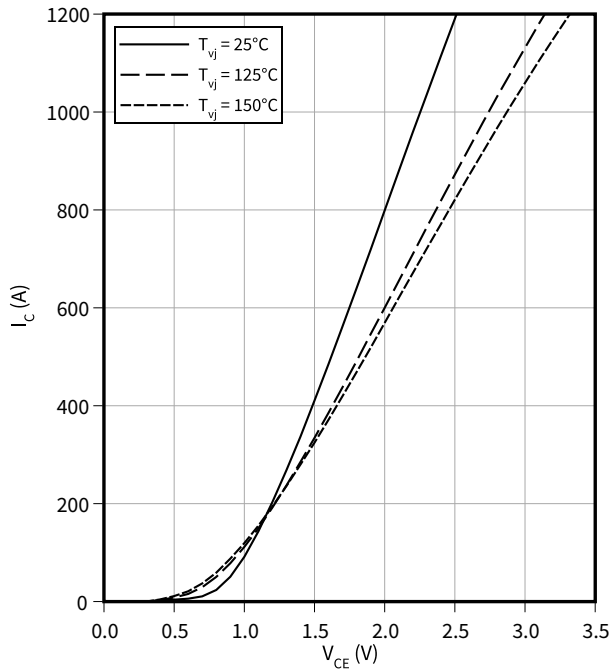
**Note:** For an analytical description of the NTC characteristics please refer to AN2009-10, chapter 4.

5 Characteristics diagrams

Output characteristic (typical), IGBT, Inverter

$I_C = f(V_{CE})$

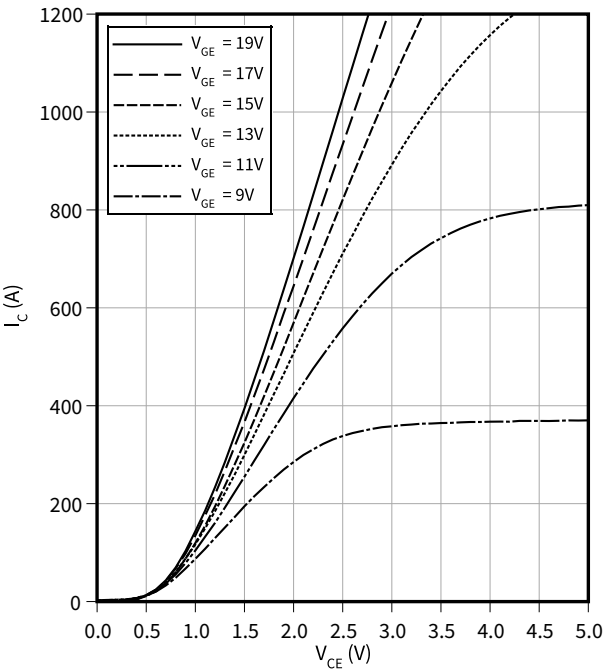
$V_{GE} = 15\text{ V}$



Output characteristic field (typical), IGBT, Inverter

$I_C = f(V_{CE})$

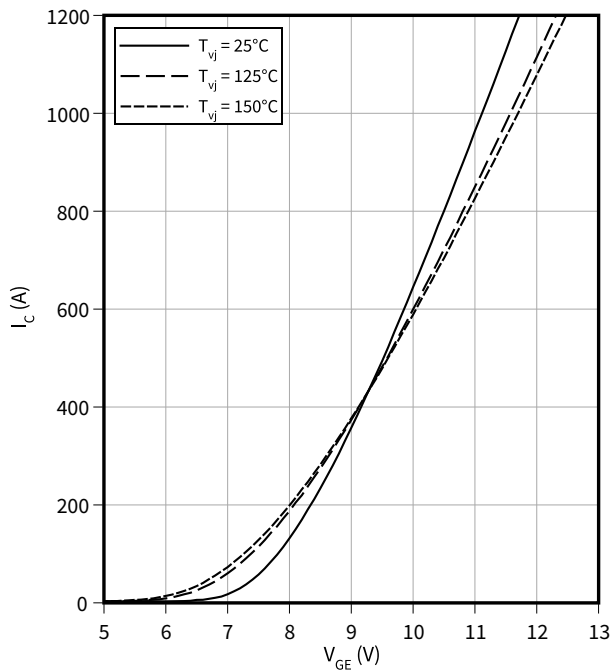
$T_{vj} = 150^\circ\text{C}$



Transfer characteristic (typical), IGBT, Inverter

$I_C = f(V_{GE})$

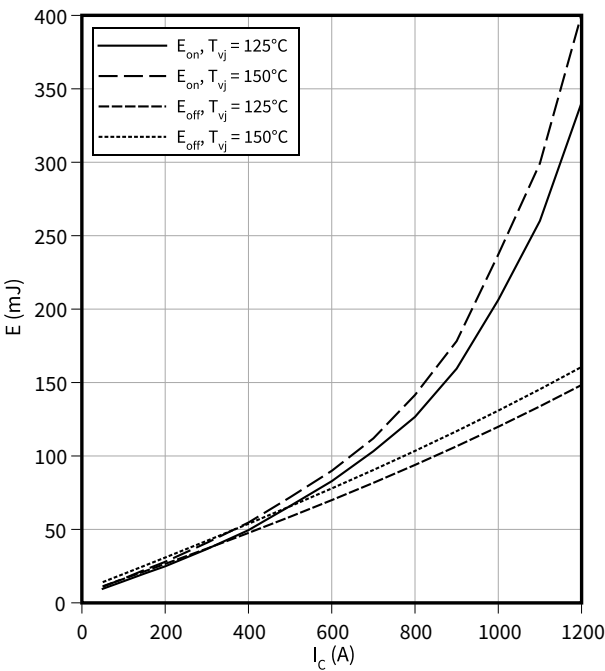
$V_{CE} = 20\text{ V}$



Switching losses (typical), IGBT, Inverter

$E = f(I_C)$

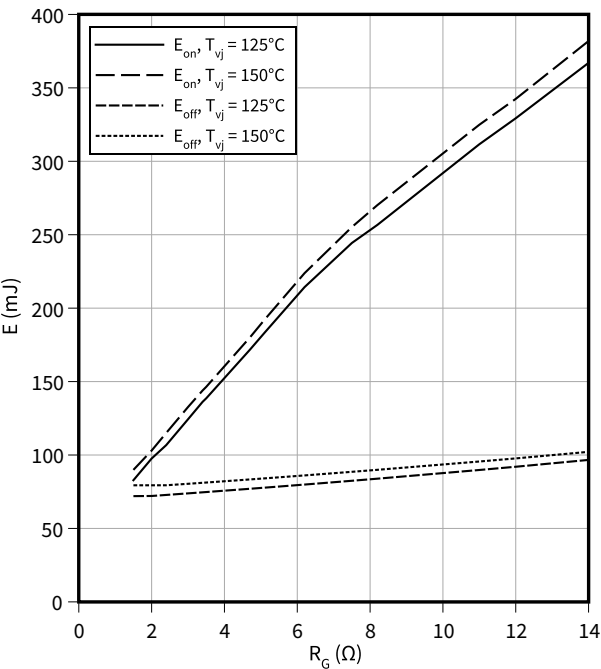
$R_{Goff} = 1.5\ \Omega$ ,  $R_{Gon} = 1.5\ \Omega$ ,  $V_{GE} = \pm 15\text{ V}$ ,  $V_{CC} = 600\text{ V}$



5 Characteristics diagrams

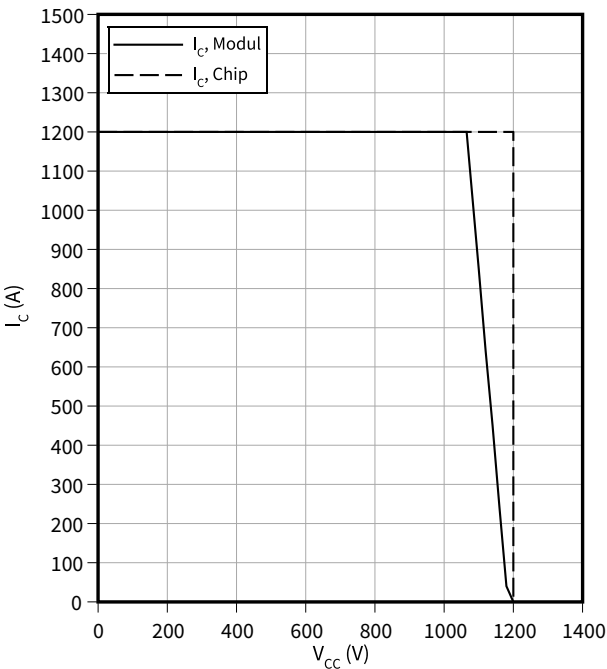
Switching losses (typical), IGBT, Inverter

$E = f(R_G)$   
 $V_{GE} = \pm 15\text{ V}$ ,  $I_C = 600\text{ A}$ ,  $V_{CC} = 600\text{ V}$



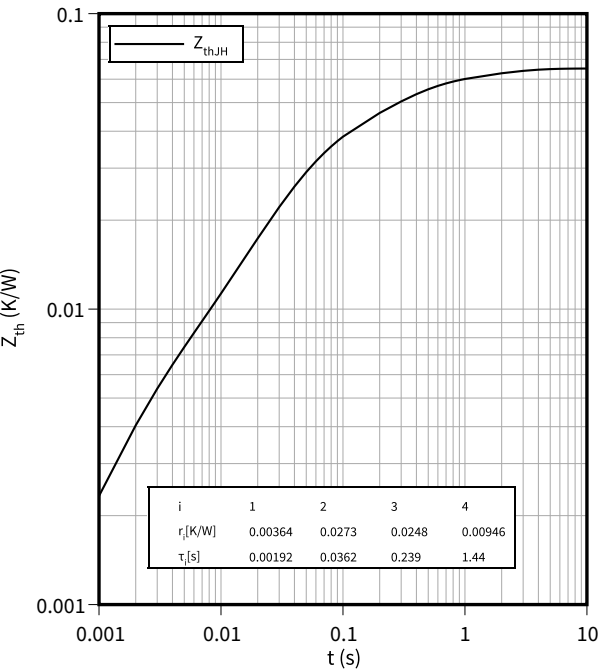
Reverse bias safe operating area (RBSOA), IGBT, Inverter

$I_C = f(V_{CC})$   
 $R_{Goff} = 1.5\text{ }\Omega$ ,  $V_{GE} = \pm 15\text{ V}$ ,  $T_{vj} = 150\text{ }^\circ\text{C}$



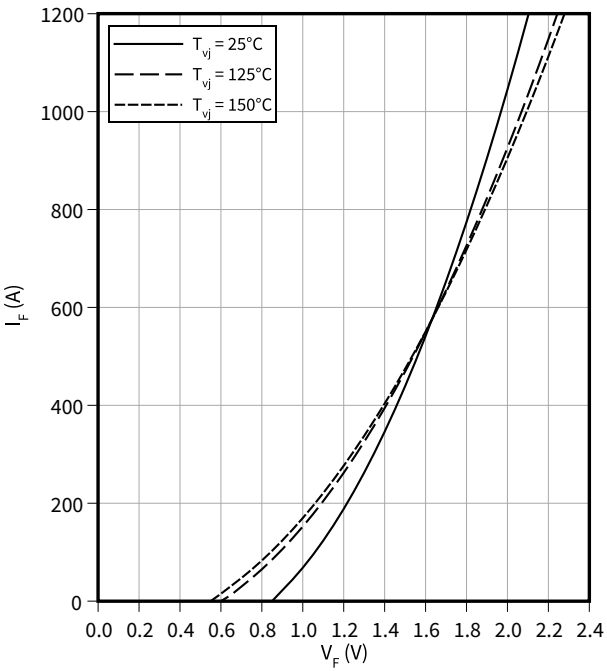
Transient thermal impedance, IGBT, Inverter

$Z_{th} = f(t)$



Forward characteristic (typical), Diode, Inverter

$I_F = f(V_F)$

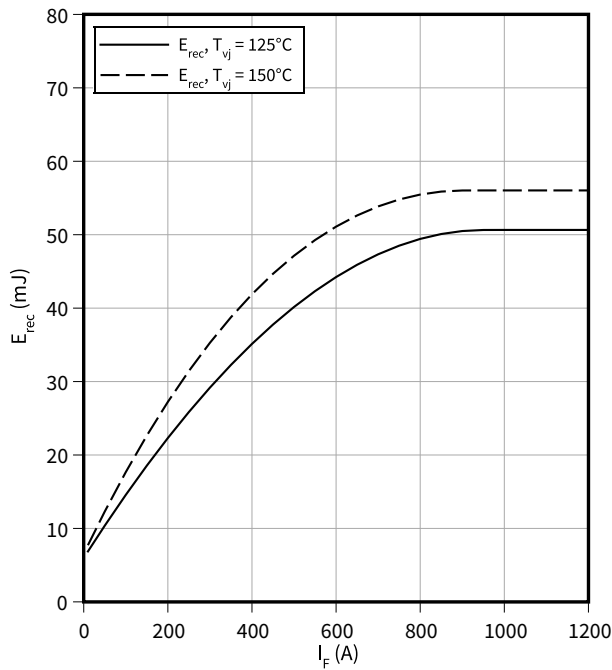




5 Characteristics diagrams

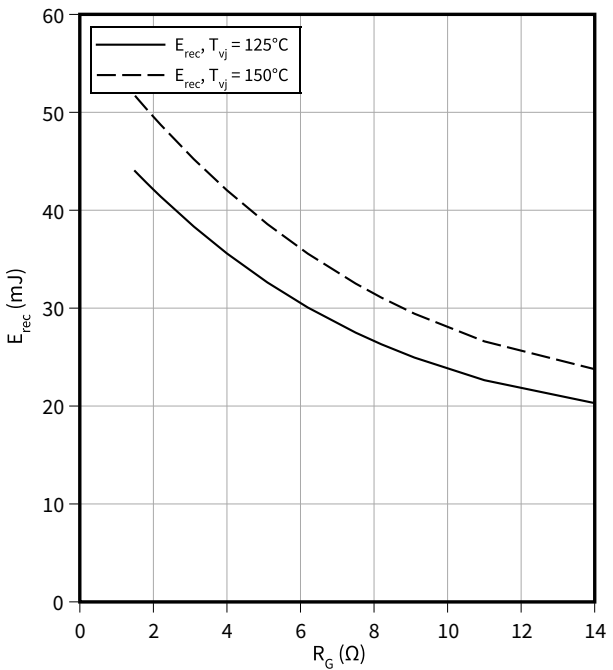
Switching losses (typical), Diode, Inverter

$E_{rec} = f(I_F)$   
 $R_{Gon} = 1.5 \Omega, V_{CC} = 600 V$



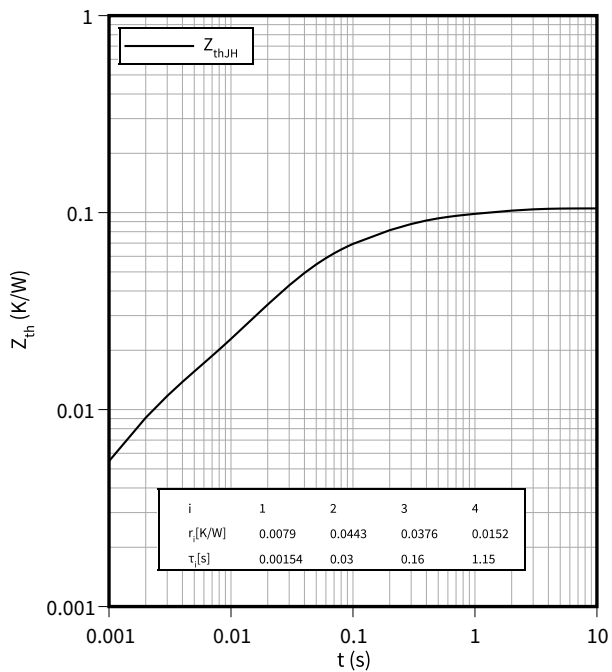
Switching losses (typical), Diode, Inverter

$E_{rec} = f(R_G)$   
 $I_F = 600 A, V_{CC} = 600 V$



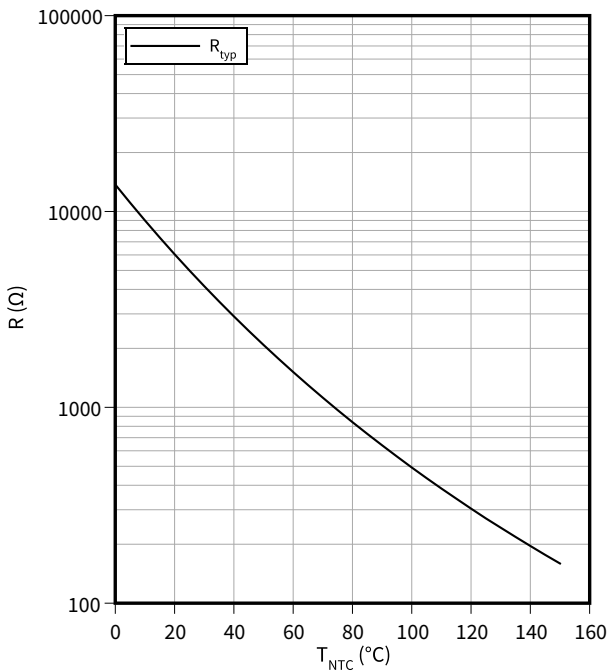
Transient thermal impedance, Diode, Inverter

$Z_{th} = f(t)$



Temperature characteristic (typical), NTC-Thermistor

$R = f(T_{NTC})$



6 Circuit diagram

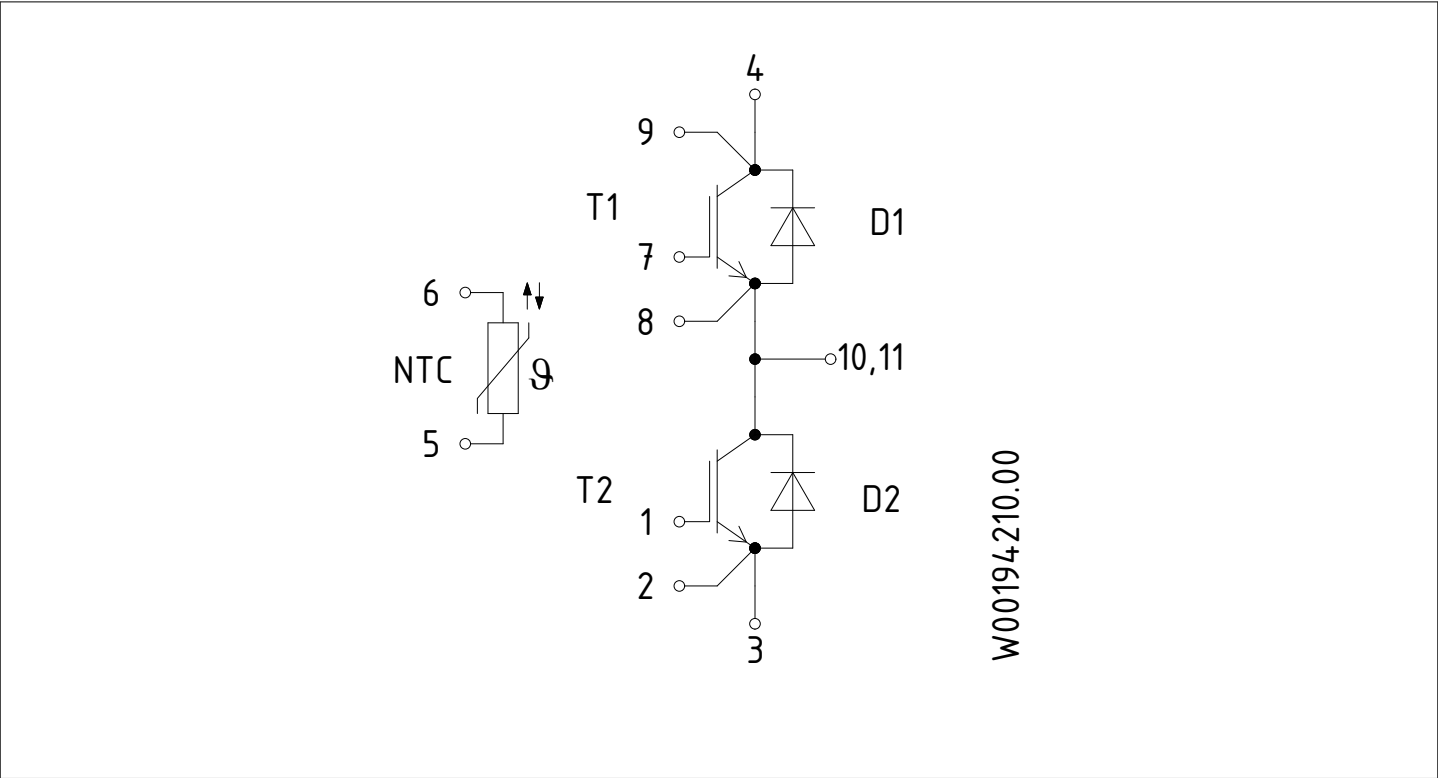


Figure 1

### Figure 2

8 Module label code

| Module label code       |                                                                                     |                         |                 |
|-------------------------|-------------------------------------------------------------------------------------|-------------------------|-----------------|
| Code format             | Data Matrix                                                                         |                         | Barcode Code128 |
| Encoding                | ASCII text                                                                          |                         | Code Set A      |
| Symbol size             | 16x16                                                                               |                         | 23 digits       |
| Standard                | IEC24720 and IEC16022                                                               |                         | IEC8859-1       |
| Code content            | <i>Content</i>                                                                      | <i>Digit</i>            | <i>Example</i>  |
|                         | Module serial number                                                                | 1 – 5                   | 71549           |
|                         | Module material number                                                              | 6 - 11                  | 142846          |
|                         | Production order number                                                             | 12 - 19                 | 55054991        |
|                         | Date code (production year)                                                         | 20 – 21                 | 15              |
|                         | Date code (production week)                                                         | 22 – 23                 | 30              |
| Example                 |   |                         |                 |
|                         |  |                         |                 |
| 71549142846550549911530 |                                                                                     | 71549142846550549911530 |                 |

Figure 3

## Revision history

| Document revision | Date of release | Description of changes                                                                                                                              |
|-------------------|-----------------|-----------------------------------------------------------------------------------------------------------------------------------------------------|
| V1.0              | 2012-08-21      | Target datasheet                                                                                                                                    |
| V3.0              | 2017-07-19      | Final datasheet                                                                                                                                     |
| n/a               | 2020-09-01      | Datasheet migrated to a new system with a new layout and new revision number schema: target or preliminary datasheet = 0.xy; final datasheet = 1.xy |
| 1.10              | 2024-03-15      | Final datasheet                                                                                                                                     |
| 1.20              | 2025-05-22      | Final datasheet                                                                                                                                     |
| 1.30              | 2025-08-19      | Final datasheet                                                                                                                                     |

## Trademarks

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**Document reference**  
**IFX-AAX171-005**

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